SQ2301ES

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Vishay Siliconix

Automotive P-Channel 20 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-20				
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.120				
$R_{DS(on)}\left(\Omega\right)$ at V_{GS} = -2.5 V	0.180				
I _D (A)	-3.9				
Configuration	Single				

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified ^d
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

GC

P-Channel MOSFET



RoHS COMPLIANT HALOGEN FREE

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$R_{DS(on)}(\Omega)$ at V_{GS} = -4.5 V	0.120
$R_{DS(on)}(\Omega)$ at V_{GS} = -2.5 V	0.180
I _D (A)	-3.9
Configuration	Single

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2301ES (for detailed order number please see <u>www.vishay.com/doc?79771</u>)

ABSOLUTE MAXIMUM RATINGS ((T _C = 25 °C, unles	s otherwise noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	-20	V
Gate-source voltage		V _{GS}	± 8	V
Continuous drain current	T _C = 25 °C	1	-3.9	
	T _C = 125 °C	I _D	-2.2	
Continuous source current (diode conduction)		I _S	-3.7	А
Pulsed drain current ^a		I _{DM}	-15	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-9	
Single pulse avalanche energy	L = 0.1 IIIH	E _{AS}	4	mJ
Maximum power dissipation ^a	T _C = 25 °C	D	3	w
	T _C = 125 °C	P _D	1	
Operating junction and storage temperature ran	ige	T _J , T _{stg}	-55 to + 175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^c	R _{thJA}	166	°C/W	
Junction-to-case (drain)		R _{thJF}	50	0/10	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR-4 material)

d. Parametric verification ongoing

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SPECIFICATIONS (T _C = 25 °C	, unless otherv	vise noted)					
PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static					•		
Drain-source breakdown voltage	V _{DS}	V _{GS}	V _{GS} = 0, I _D = -250 μA		-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V_{GS} , I_{D} = -250 μ A	-0.45	-	-1.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 8 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -20 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -20 V, T _J = 125 °C	-	-	-50	μA
		$V_{GS} = 0 V$	V _{DS} = -20 V, T _J = 175 °C	-	-	-150	
On-state drain current ^a	I _{D(on)}	$V_{GS} = -4.5 V$	$V_{DS} \ge 5 V$	-8	-	-	А
	Р	$V_{GS} = -4.5 V$	I _D = -2.8 A	-	0.080	0.120	
Drain-source on-state resistance ^a	source on-state resistance ^a $R_{DS(on)}$ $V_{GS} = -2.5 V$ $I_D = -2$	I _D = -2 A	-	0.110	0.180	Ω	
Forward transconductance a	g _{fs}	V _{DS} =	V _{DS} = -1.6 V, I _D = -2.8 A		7	-	S
Dynamic ^b		·					
Input capacitance	C _{iss}			-	340	425	
Output capacitance	C _{oss}	V _{GS} = 0 V V _{DS} =	V _{DS} = -10 V, f = 1 MHz	-	80	100	pF
Reverse transfer capacitance	C _{rss}			-	55	70	
Total gate charge ^c	Qg			-	5	8	
Gate-source charge ^c	Q _{gs}	V _{GS} = -4.5 V	$_{\rm S}$ = -4.5 V V _{DS} = -10 V, I _D = -2.8 A	-	0.7	-	nC
Gate-drain charge ^c	Q _{gd}			-	1.3	-	
Gate resistance	R _g	f = 1 MHz		5.5	10	14.5	Ω
Turn-on delay time ^c	t _{d(on)}			-	15	22	
Rise time ^c	t _r	$\begin{array}{l} V_{DD}=\text{-10 V, R}_{L}=\text{10 }\Omega\\ \text{I}_{D}\cong\text{-1 A, V}_{\text{GEN}}=\text{-4.5 V, R}_{g}=\text{1 }\Omega \end{array}$		-	14	21	ns
Turn-off delay time ^c	t _{d(off)}			-	30	45	
Fall time ^c	t _f	1		-	9	15	1
Source-Drain Diode Ratings and Chara	cteristics ^b						
Pulsed current ^a	I _{SM}			-	-	-15	А
Forward voltage	V _{SD}	I _F =	-1.6 A, V _{GS} = 0	-	-0.8	-1.2	V

Notes

e. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

f. Guaranteed by design, not subject to production testing

g. Independent of operating temperature

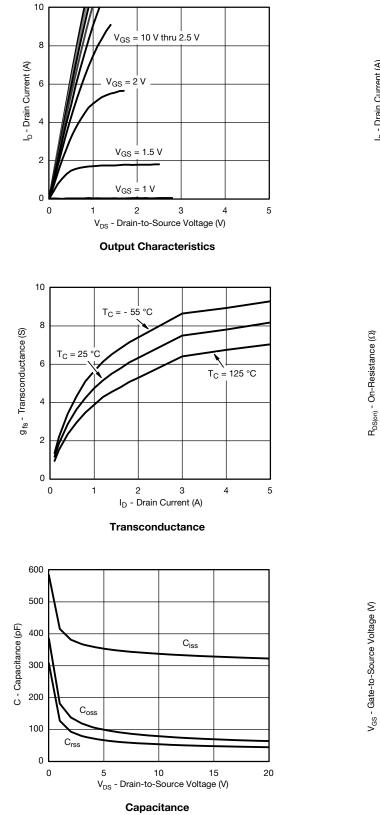
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

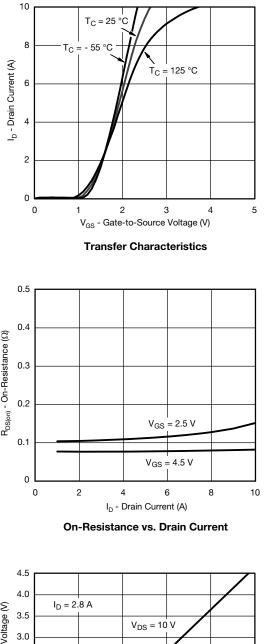
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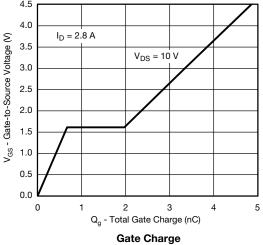


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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)







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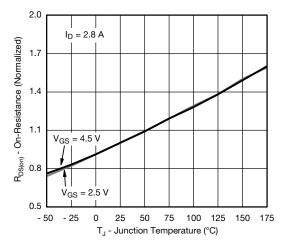
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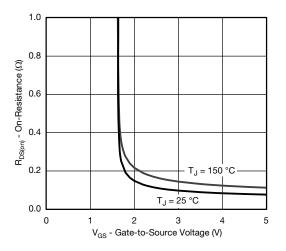
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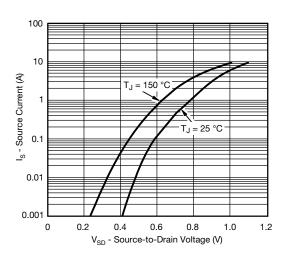
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



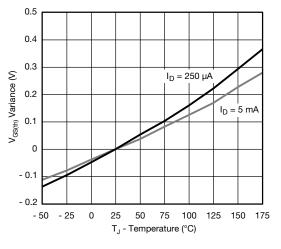
On-Resistance vs. Junction Temperature



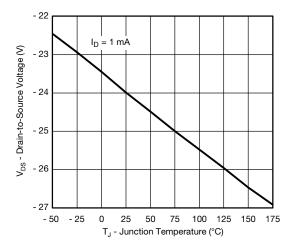
On-Resistance vs. Gate-to-Source Voltage



Source-Drain Diode Forward Voltage







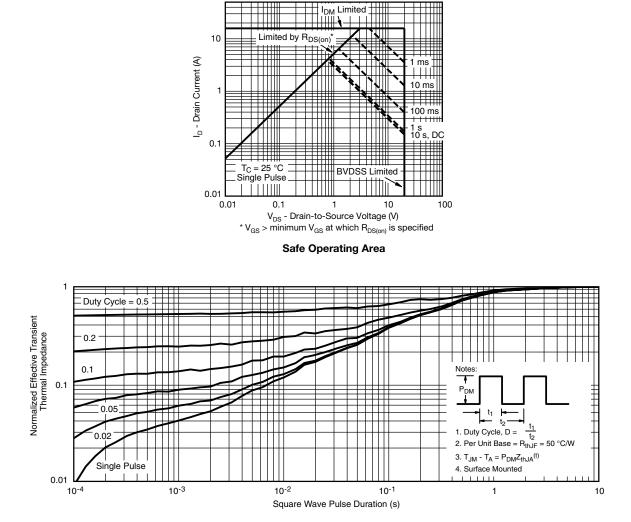
Drain Source Breakdown vs. Junction Temperature

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



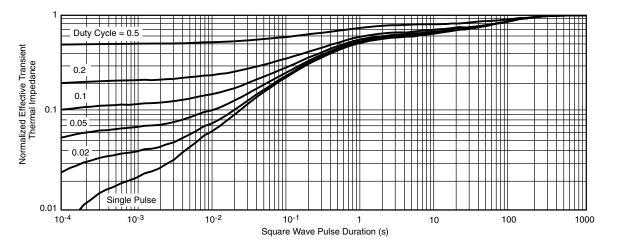
Normalized Thermal Transient Impedance, Junction-to-Foot



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

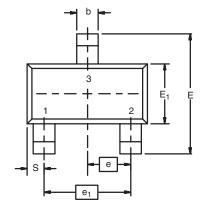
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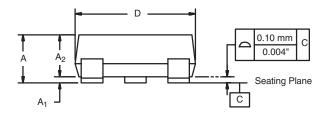


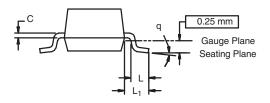
Package Information

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SOT-23 (TO-236): 3-LEAD





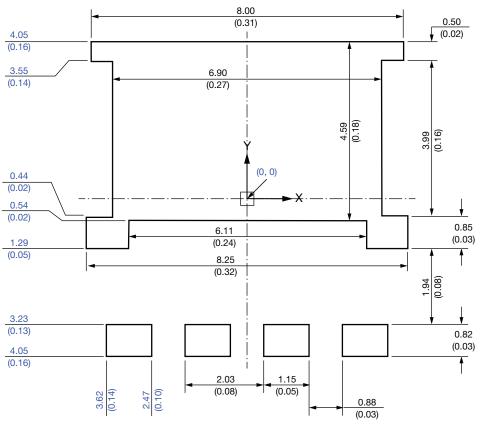


Dim	MILLIN	METERS	INCHES			
Dim	Min	Max	Min	Мах		
Α	0.89	1.12	0.035	0.044		
A ₁	0.01	0.10	0.0004	0.004		
A ₂	0.88	1.02	0.0346	0.040		
b	0.35	0.50	0.014	0.020		
С	0.085	0.18	0.003	0.007		
D	2.80	3.04	0.110	0.120		
E	2.10	2.64	0.083	0.104		
E ₁	1.20	1.40	0.047	0.055		
е	0.95	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref			
L	0.40	0.60	0.016	0.024		
L ₁	0.64 Ref		0.025	5 Ref		
S	0.50 Ref		0.020 Ref			
q	3°	8°	3°	8°		



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Recommended Minimum PADs for PowerPAK® 8 x 8L Single



Dimensions in millimeters (inches)

Note

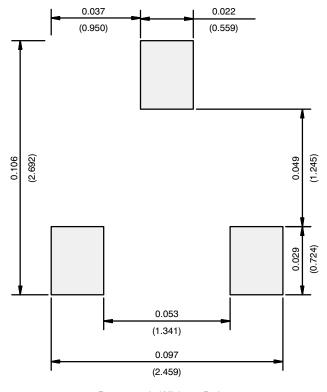
• Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.



Application Note 826

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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